ON Semiconductor

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Power MOSFET 23 Amps, 25 Volts

N-Channel D²PAK

Designed for low voltage, high speed switching applications in power supplies, converters and power motor controls and bridge circuits.

Features

• Pb-Free Packages are Available

Typical Applications

- Planar HD3e Process for Fast Switching Performance
- Low R_{DS(on)} to Minimize Conduction Loss
- Low Ciss to Minimize Driver Loss
- Low Gate Charge
- Optimized for High Side Switching Requirements in High-Efficiency DC-DC Converters

MAXIMUM RATINGS (T_J = 25°C unless otherwise specified)

Parameter	Symbol	Value	Unit
Drain-to-Source Voltage	V_{DSS}	25	Vdc
Gate-to-Source Voltage - Continuous	V _{GS}	±20	Vdc
Drain Current - Continuous @ T_A = 25°C, Limited by Chip - Continuous @ T_A = 25°C, Limited by Package - Single Pulse (t_p = 10 μ s)	I _D I _D I _{DM}	23 6.0 60	А
Total Power Dissipation @ T _A = 25°C	P _D	37.5	W
Operating and Storage Temperature Range	T _J , T _{stg}	-55 to 150	ç
Thermal Resistance - Junction-to-Case	$R_{\theta JC}$	3.3	°C/W
Maximum Lead Temperature for Soldering Purposes, 1/8" from case for 10 seconds	TL	260	ç

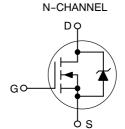
Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.



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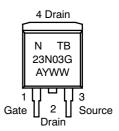
23 AMPERES, 25 VOLTS $R_{DS(on)} = 32 \text{ m}\Omega \text{ (Typ)}$



MARKING DIAGRAM & PIN ASSIGNMENTS



D²PAK CASE 418B STYLE 2



NTB23N03 = Specific Device Code A = Assembly Location

Y = Year
WW = Work Week
G = Pb-Free Package

ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 2 of this data sheet.

ELECTRICAL CHARACTERISTICS ($T_J = 25^{\circ}C$ unless otherwise specified)

Characteristics			Min	Тур	Max	Unit
OFF CHARACTERISTICS				-		
Drain-to-Source Breakdown Voltage (Note 1) (V _{GS} = 0 Vdc, I _D = 250 μAdc) Temperature Coefficient (Positive)		V(br) _{DSS}	25 -	28 -	- -	Vdc mV/°C
Zero Gate Voltage Drain Current (V _{DS} = 20 Vdc, V _{GS} = 0 Vdc) (V _{DS} = 20 Vdc, V _{GS} = 0 Vdc, T _J = 150°C)		I _{DSS}	- -	- -	1.0 10	μAdc
Gate-Body Leakage Current (V _{GS} = ±20 Vdc, V _{DS} = 0 Vdc)			-	-	±100	nAdc
ON CHARACTERISTICS (Note 1)						
Gate Threshold Voltage (Note 1) $(V_{DS} = V_{GS}, \ I_D = 250 \ \mu Adc)$ Threshold Temperature Coefficient (Negative)			1.0 -	1.8 -	2.0 -	Vdc mV/°C
Static Drain-to-Source On-Resistance (Note 1) $ (V_{GS} = 4.5 \text{ Vdc}, I_D = 6 \text{ Adc}) $ $ (V_{GS} = 10 \text{ Vdc}, I_D = 6 \text{ Adc}) $		R _{DS(on)}	1 1	50.3 32.3	60 45	mΩ
Forward Transconductance (Note 1) (V _{DS} = 10 Vdc, I _D = 6 Adc)			ı	14	-	Mhos
DYNAMIC CHARACTERISTICS						
Input Capacitance		C _{iss}	-	225	-	pF
Output Capacitance	$(V_{DS} = 20 \text{ Vdc}, V_{GS} = 0 \text{ V}, f = 1 \text{ MHz})$	C _{oss}	-	108	-	
Transfer Capacitance		C _{rss}	-	48	-	
SWITCHING CHARACTERISTICS	(Note 2)					
Turn-On Delay Time		t _{d(on)}	-	2.0	-	ns
Rise Time	(V _{GS} = 10 Vdc, V _{DD} = 10 Vdc,	t _r	-	14.9	-	
Turn-Off Delay Time	$I_D = 6 \text{ Adc}, R_G = 3 \Omega$	t _{d(off)}	-	9.9	-	
Fall Time		t _f	ı	2.0	-	
Gate Charge	(V _{GS} = 4.5 Vdc, I _D = 6 Adc, V _{DS} = 10 Vdc) (Note 1)	Q_{T}	1	3.76	-	nC
		Q ₁	-	1.7	-	
	153 10 120, (11010 1)	Q_2	-	1.6	-	
SOURCE-DRAIN DIODE CHARAC	TERISTICS					
Forward On-Voltage	$(I_S = 6 \text{ Adc}, V_{GS} = 0 \text{ Vdc}) \text{ (Note 1)}$ $(I_S = 6 \text{ Adc}, V_{GS} = 0 \text{ Vdc}, T_J = 125^{\circ}\text{C})$	V _{SD}	-	0.87 0.74	1.2 -	Vdc
Reverse Recovery Time	(I _S = 6 Adc, V _{GS} = 0 Vdc, dI _S /dt = 100 A/μs) (Note 1)	t _{rr}	-	8.7	-	ns
		t _a	-	5.2	-]
		t _b	-	3.5	-	1
Reverse Recovery Stored Charge		Q _{RR}	-	0.003	-	μС

ORDERING INFORMATION

Device	Package	Shipping [†]
NTB23N03R	D ² PAK	50 Units / Rail
NTB23N03RG	D ² PAK (Pb-Free)	50 Units / Rail
NTB23N03RT4	D ² PAK	800 Units / Tape & Reel
NTB23N03RT4G	D ² PAK (Pb-Free)	800 Units / Tape & Reel

[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

Pulse Test: Pulse Width ≤ 300 μs, Duty Cycle ≤ 2%.
 Switching characteristics are independent of operating junction temperatures.

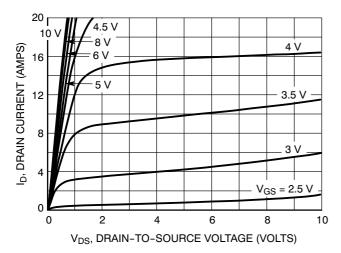


Figure 1. On-Region Characteristics

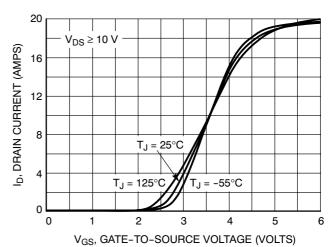


Figure 2. Transfer Characteristics

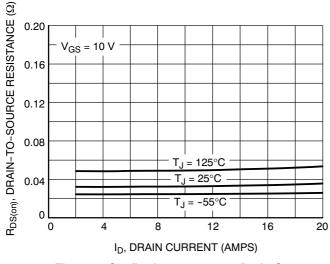


Figure 3. On-Resistance versus Drain Current and Temperature

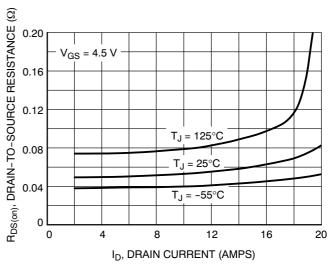


Figure 4. On-Resistance versus Drain Current and Temperature

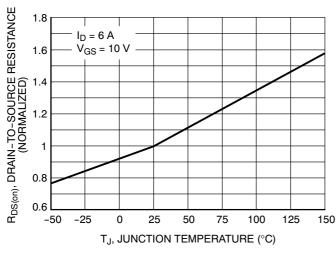


Figure 5. On–Resistance Variation with Temperature

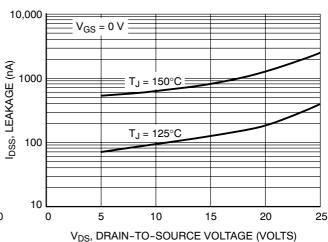


Figure 6. Drain-to-Source Leakage Current versus Voltage

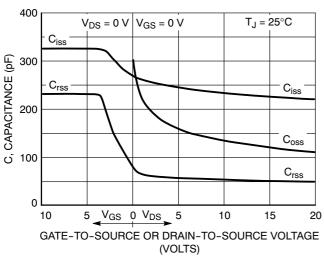


Figure 7. Capacitance Variation

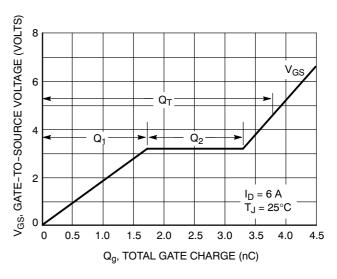


Figure 8. Gate-to-Source and Drain-to-Source Voltage versus Total Charge

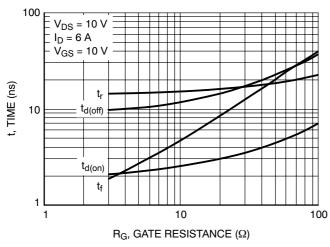


Figure 9. Resistive Switching Time Variation versus Gate Resistance

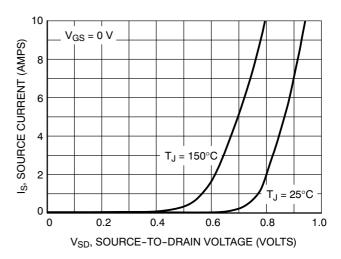
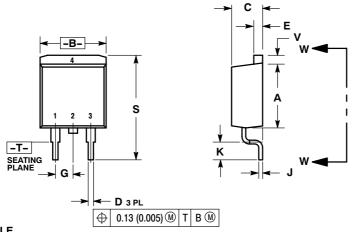


Figure 10. Diode Forward Voltage versus Current

PACKAGE DIMENSIONS

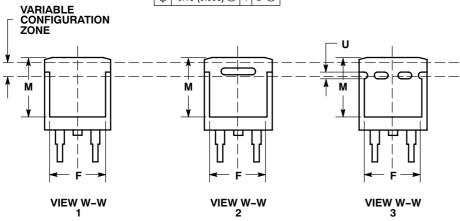




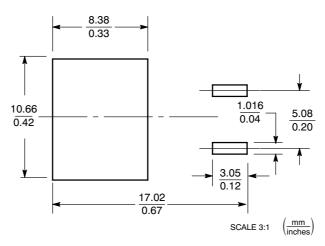
- NOTES: 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982. 2. CONTROLLING DIMENSION: INCH.

	INCHES		MILLIM	METERS	
DIM	MIN	MAX	MIN	MAX	
Α	0.340	0.380	8.64	9.65	
В	0.380	0.405	9.65	10.29	
С	0.160	0.190	4.06	4.83	
D	0.020	0.036	0.51	0.92	
Е	0.045	0.055	1.14	1.40	
F	0.310		7.87		
G	0.100 BSC		2.54 BSC		
J	0.018	0.025	0.46	0.64	
K	0.090	0.110	2.29	2.79	
М	0.280		7.11		
S	0.575	0.625	14.60	15.88	
V	0.045	0.055	1.14	1.40	

- STYLE 2: PIN 1. GATE 2. DRAIN 3. SOURCE



SOLDERING FOOTPRINT*



*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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